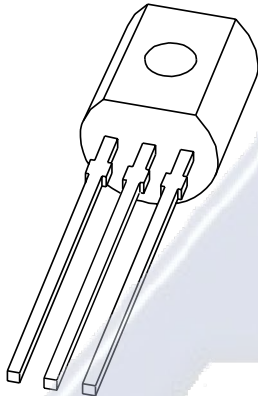


DISCRETE SEMICONDUCTORS

DATA SHEET



PSS9012 series

**20 V PNP general purpose
transistors**

Product specification
Supersedes data of 2003 May 15

2004 Aug 10

20 V PNP general purpose transistors

PSS9012 series

FEATURES

- High power dissipation: 710 mW
- Low collector capacitance
- Low collector-emitter saturation voltage
- High current capability.

APPLICATIONS

- General purpose switching and amplification.

DESCRIPTION

PNP general purpose transistor in a SOT54 (TO-92) leaded plastic package. NPN complement: PSS9013 series.

MARKING

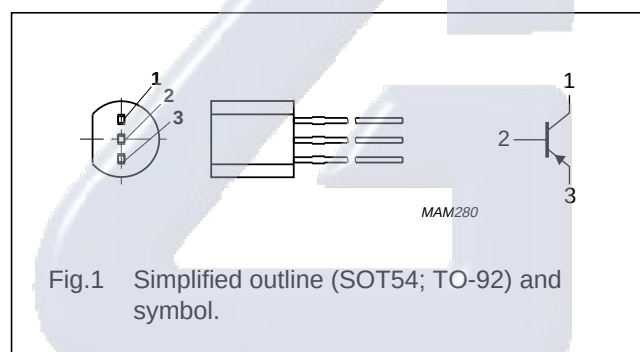
TYPE NUMBER	MARKING CODE
PSS9012G	S9012G
PSS9012H	S9012H

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V_{CEO}	collector-emitter voltage	-20	V
I_C	collector current (DC)	-500	mA
I_{CM}	peak collector current	-1	A

PINNING

PIN	DESCRIPTION
1	collector
2	base
3	emitter



LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	-	-40	V
V_{CEO}	collector-emitter voltage	open base	-	-20	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
I_C	collector current (DC)		-	-500	mA
I_{CM}	peak collector current		-	-1	A
I_{BM}	peak base current		-	-100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^{\circ}\text{C}$; note 1	-	710	mW
T_{stg}	storage temperature		-65	+150	$^{\circ}\text{C}$
T_j	junction temperature		-	150	$^{\circ}\text{C}$
T_{amb}	operating ambient temperature		-65	+150	$^{\circ}\text{C}$

Note

1. Device mounted on a FR4 printed-circuit board, single-sided copper, tinplated and standard footprint.

20 V PNP general purpose transistors

PSS9012 series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	in free air; note 1	175	K/W

Note

1. Device mounted on a FR4 printed-circuit board, single-sided copper, tinplated and standard footprint.

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector-base cut-off current	$V_{CB} = -35\text{ V}; I_E = 0$	–	–	–100	nA
		$V_{CB} = -35\text{ V}; I_E = 0; T_j = 150\text{ °C}$	–	–	–50	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -5\text{ V}; I_C = 0$	–	–	–100	nA
h_{FE}	DC current gain	$V_{CE} = -1\text{ V}; I_C = -500\text{ mA}$	40	–	–	
h_{FE}	DC current gain PSS9012G PSS9012H	$V_{CE} = -1\text{ V}; I_C = -50\text{ mA}$	112 144	– –	166 202	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -100\text{ mA}; I_B = -10\text{ mA}$	–	–60	–250	mV
		$I_C = -500\text{ mA}; I_B = -50\text{ mA}$	–	–230	–600	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = -500\text{ mA}; I_B = -50\text{ mA}$	–	–1	–1.2	V
V_{BEon}	base-emitter turn on voltage	$V_{CE} = -1\text{ V}; I_C = -100\text{ mA}$	–	–760	–1000	mV
C_c	collector capacitance	$V_{CB} = -6\text{ V}; I_E = I_e = 0;$ $f = 1\text{ MHz}$	–	6	–	pF

Electrónica S.A. de C.V.

20 V PNP general purpose transistors

PSS9012 series

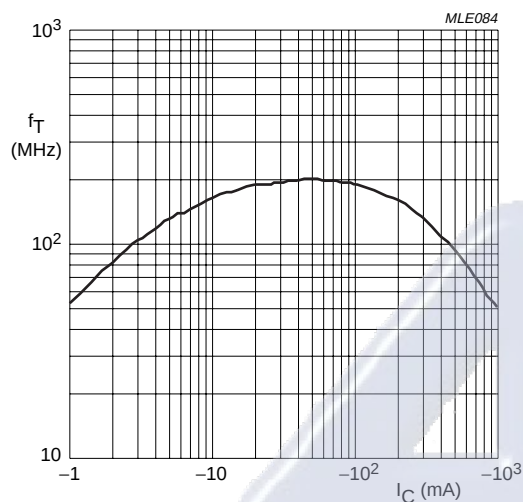
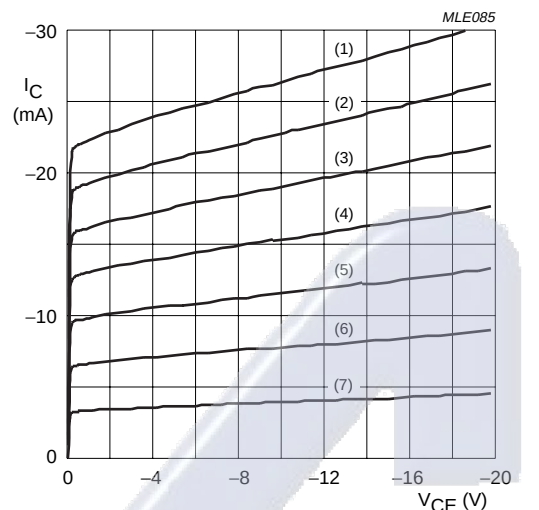
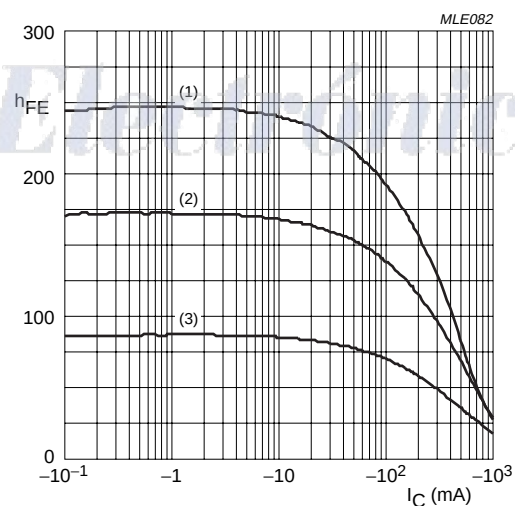


Fig.2 Transition frequency as a function of collector current; typical values.



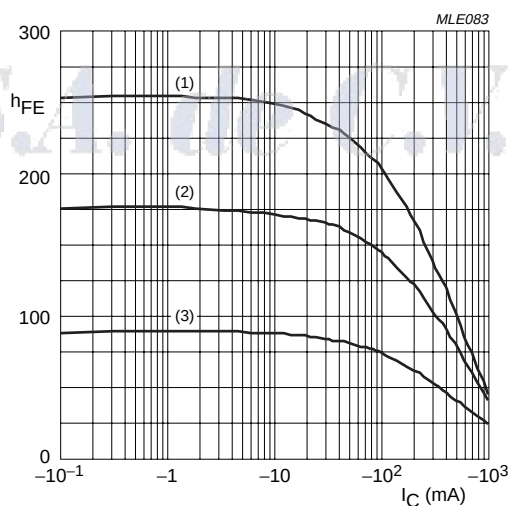
- (1) $I_B = -140$ μ A. (4) $I_B = -80$ μ A. (7) $I_B = -20$ μ A.
 (2) $I_B = -120$ μ A. (5) $I_B = -60$ μ A.
 (3) $I_B = -100$ μ A. (6) $I_B = -40$ μ A.

Fig.3 Collector current as a function of collector-emitter voltage; typical values.



- (1) $T_{amb} = 100$ °C.
 (2) $T_{amb} = 25$ °C.
 (3) $T_{amb} = -55$ °C.

Fig.4 DC current gain as a function of collector current; typical values.

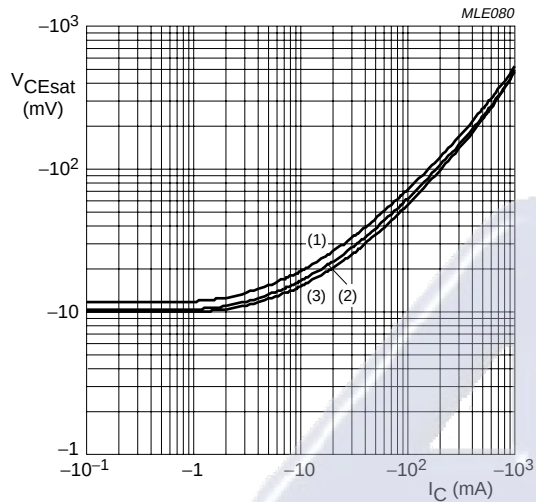


- (1) $T_{amb} = 100$ °C.
 (2) $T_{amb} = 25$ °C.
 (3) $T_{amb} = -55$ °C.

Fig.5 DC current gain as a function of collector current; typical values.

20 V PNP general purpose transistors

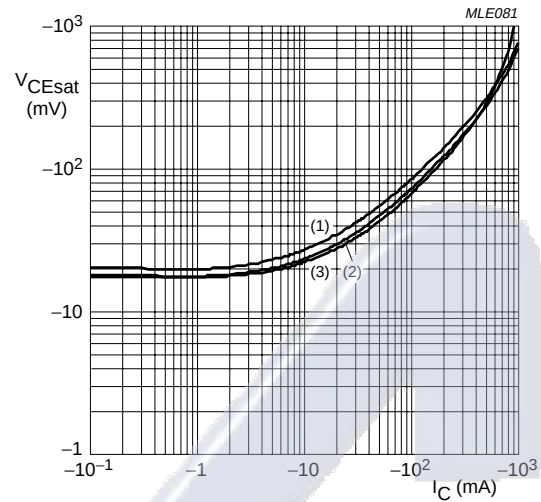
PSS9012 series



$I_C/I_B = 10$.

- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$.
- (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$.
- (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$.

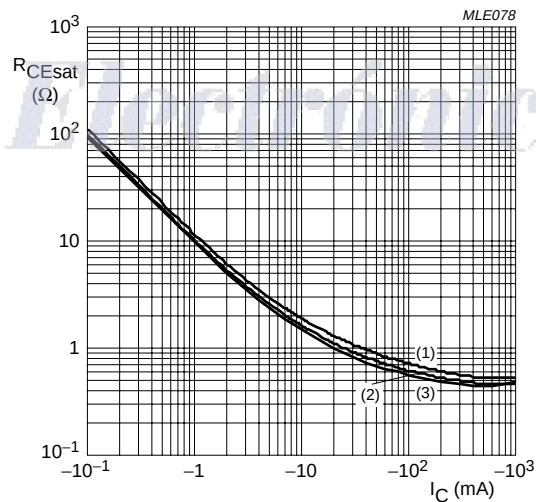
Fig.6 Collector-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 20$.

- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$.
- (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$.
- (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$.

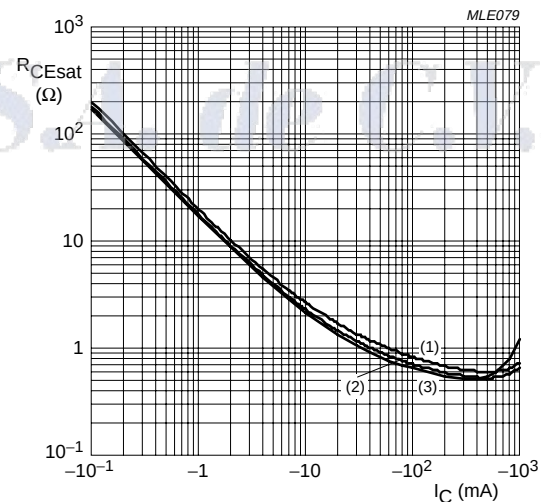
Fig.7 Collector-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$.
- (2) $T_{amb} = 25\text{ }^{\circ}\text{C}$.
- (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$.

Fig.8 Collector-emitter equivalent on-resistance as a function of collector current; typical values.



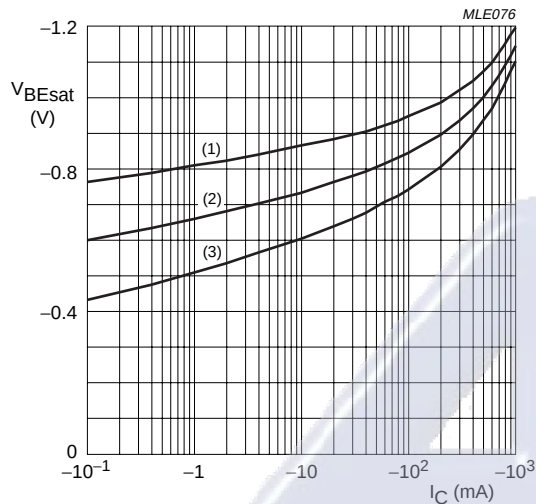
$I_C/I_B = 20$.

- (1) $T_{amb} = 25\text{ }^{\circ}\text{C}$.
- (2) $T_{amb} = 100\text{ }^{\circ}\text{C}$.
- (3) $T_{amb} = -55\text{ }^{\circ}\text{C}$.

Fig.9 Collector-emitter equivalent on-resistance as a function of collector current; typical values.

20 V PNP general purpose transistors

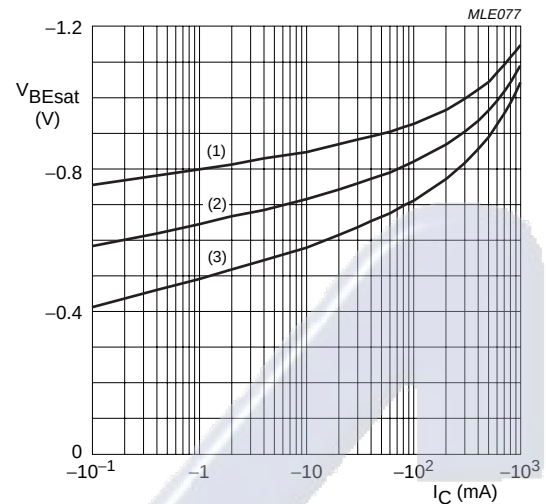
PSS9012 series



$I_C/I_B = 10$.

- (1) $T_{amb} = -55^\circ\text{C}$.
- (2) $T_{amb} = 25^\circ\text{C}$.
- (3) $T_{amb} = 100^\circ\text{C}$.

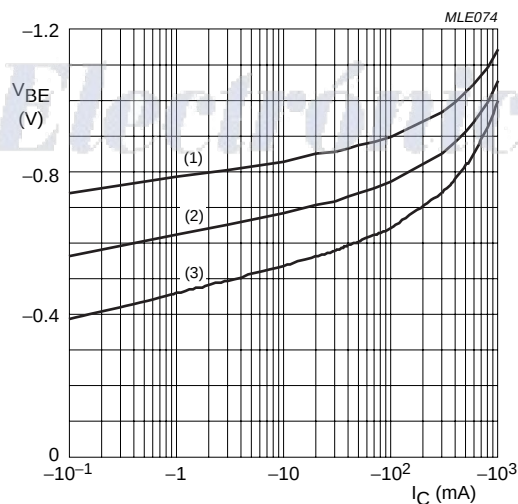
Fig.10 Base-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 20$.

- (1) $T_{amb} = -55^\circ\text{C}$.
- (2) $T_{amb} = 25^\circ\text{C}$.
- (3) $T_{amb} = 100^\circ\text{C}$.

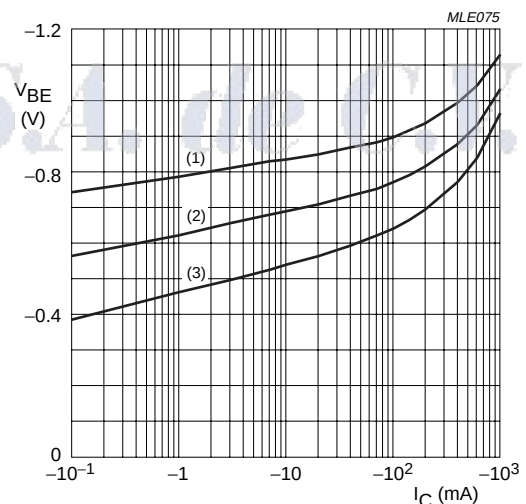
Fig.11 Base-emitter saturation voltage as a function of collector current; typical values.



$V_{CE} = -1\text{ V}$.

- (1) $T_{amb} = -55^\circ\text{C}$.
- (2) $T_{amb} = 25^\circ\text{C}$.
- (3) $T_{amb} = 100^\circ\text{C}$.

Fig.12 Base-emitter voltage as a function of collector current; typical values.



$V_{CE} = -2\text{ V}$.

- (1) $T_{amb} = -55^\circ\text{C}$.
- (2) $T_{amb} = 25^\circ\text{C}$.
- (3) $T_{amb} = 100^\circ\text{C}$.

Fig.13 Base-emitter voltage as a function of collector current; typical values.

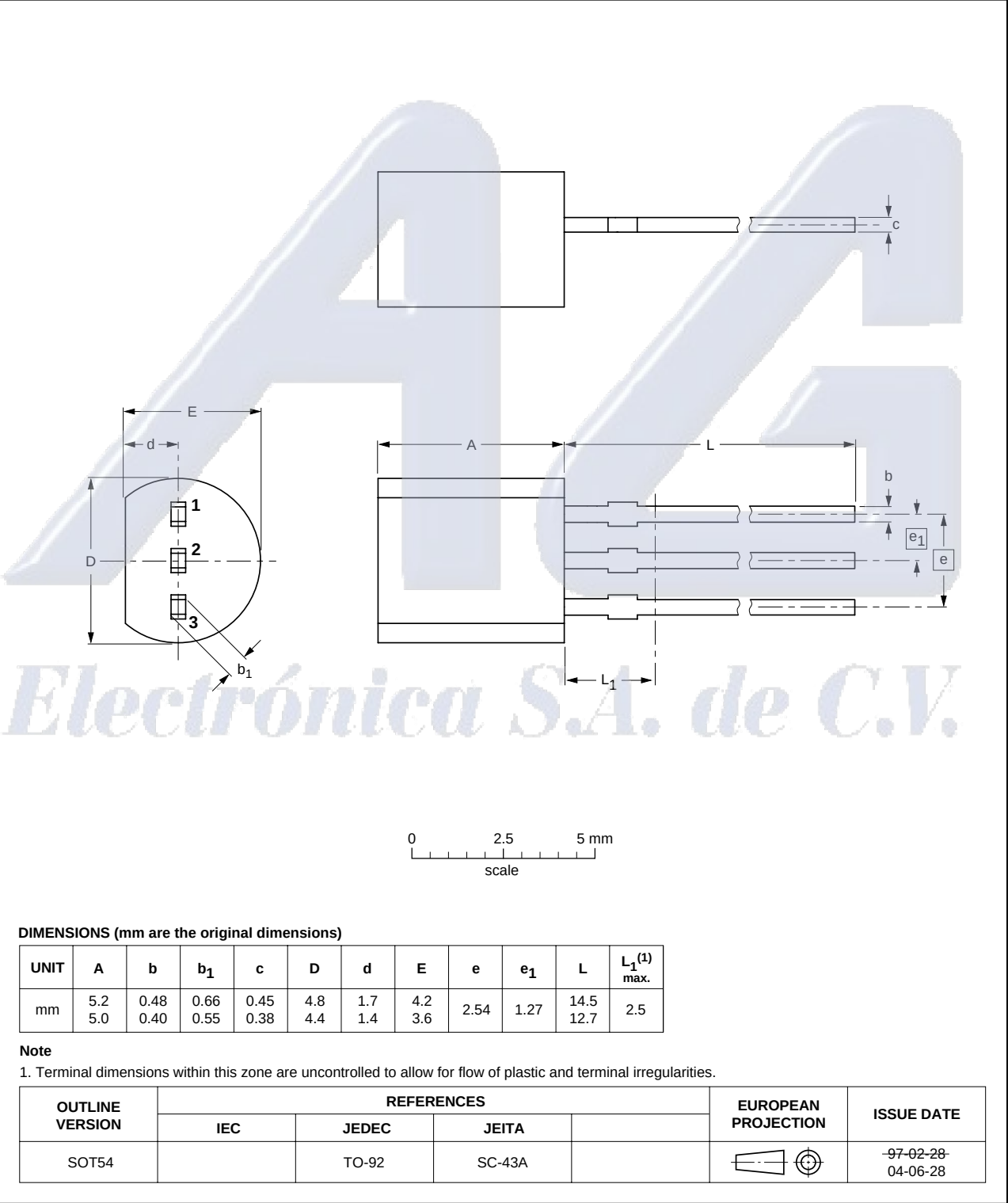
20 V PNP general purpose transistors

PSS9012 series

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



20 V PNP general purpose transistors

PSS9012 series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
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Printed in The Netherlands

R75/02/pp9

Date of release: 2004 Aug 10

Document order number: 9397 750 13684

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